PTO/SB/14 (08-05)
Approved for use through 07/31/2006 OMB 0651-0032
U.S. Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE

	Under the Pa	perwork Reduction	Act of 19	95, no per	rsons are requ	uired to respo	nd to a coll	lection of it	nformation unless it	contains a valid OMB con	itrol number
Annli	iontion Dat	a Sheet 37	CED	4 76	Attorne	y Docket	Numbe	r 113	18-71		
Appii	cation Dat	a Sileet Si	CFK	1.70	Applica	tion Num	ber				
Title of	Invention	ERTICAL POWER MOSFET WITH ENHANCED BASE REGION									
bibliogra This doc	phic data arrang cument may be	ed in a format sp	edfied b	by the Un and sub	ited States I mitted to the	Patent and	Frademar	k Office a	is outlined in 37	ollowing form contains CFR 1 76 nic Filing System (EF	
ecre	cy Order	37 CFR	5.2								
										Secrecy Order pur electronically.)	suant to
ppli	cant Info	rmation:									
Applic	ant 1									Remove	
Applic	ant Authorit	v • Inventor	OLe	egal Rep	oresentativ	e under 3	U.S.C.	117	OParty of Ir	terest under 35 U.S	C. 118
	Given Nam			M	iddle Nar	ne		Fa	mily Name		Suffix
	Dah Wen							Tsa	ing		
Resid	ence Inform	ation (Select	One)	⊕ US	Residenc	v ()	Non US	Residen	cy Activ	e US Military Service	9
City	Bend			State	Province	OR	Cou	ntry of	Residence i	US	
Citizer	nship under	37 CFR 1.41(b) i	TW							
Mailin	g Address of	Applicant:	-								
Addre	ss 1	60309 Ta	all Pine								
Addre	ss 2										
City	Bend					St	ate/Pro	vince	OR		
Postal	Code	97702				Country	i US				
A										Remove	
Applic	ant 2 ant Authorit	. (Inventor	Ole	egal Rec	presentativ	e under 3	SUSC	117	○Party of Ir	iterest under 35 U/S	C 118
	Given Nam		Ü		iddle Nar				mily Name		Suffix
····	John			w				Mo			II
Resid		ation (Select	Onel	1	Residenc	v 0	Non US			e US Military Service	
City	Bend	ation (ocicet			Province		_		Residence	us	
		37 CFR 1.41(b) i	US		0.1	000	, 0.	rtcoideiroc ·		
	g Address of		υ, .	00							
Addre		504 NW	Copare	nee.							
Addre			oongre								
City	Bend					9	ate/Pro	vince	OR		
Postal		97701						vilice	OK		
Postai	Loge	9//01				Country	n US				
Applic		_	_						1-	Remove	
	ant Authorit		Ore		presentativ		U.S.C.	_	ļ ,	iterest under 35 U.S	_
Prefix	Given Nam	e		_	iddle Nar	ne		_	mily Name		Suffix
	Douglas			A.				Pik	•		Jr.
_		ation (Select	One)	\sim	Residenc		Non US		, ,	e US Military Service	9
City	Bend			State	Province	OR	Cou	ntry of	Residence i	US	

Application Number

Application Data Sheet 37 CFR 1.76

1138-71

Title of Ir	Title of Invention SELF ALIGNED VERTICAL POWER MOSFET WITH ENHANCED BASE REGION													
Citizens	hip under	37 C	FR 1.41()	b) i	US	3								
Mailing .	Address	of App	olicant:	_										
Address	Address 1 60666 Newcastle Drive													
Address	3 2													
City	Bend							Stat	e/Provi	nce	OR			
Postal C	ode		97702				Co	untryi	US					
Applica	nt 4											Remo	ve	
	nt Author	tv 💿	Inventor	Or	egal	Representativ	ve uno	ler 35 l	J.S.C. 11	7	OParty of Ir	nterest und	der 35 U.S.	C: 118
	Given Nar					Middle Na	me			Fan	nily Name			Suffix
	Theodore					0.				Mey	er			
Resider	nce Inform	nation	(Select	One)	•	US Residenc	y	O No	n US Re	sidenc	y Activ	e US Milit	ary Service	
City I	Bend				St	ate/Province	e (OR	Countr	y of F	Residence i	US		
Citizens	hip unde	37 C	FR 1.41(I	b) i	US	3								
Mailing	Address	of App	licant:											
Address	: 1		60534 Ta	ill Pine	•									
Address	s 2													
City	Bend					State/Province OR								
Postal C	ode		97702			Countryi US								
						al Inventor I Add button.	Inform	nation	blocks	may	be	Add		
Corres	ponde	псе	Inform	atio	n:									
	ther Cust her inforn					ete the Corr a).	espo	ndend	e Inform	nation	n section be	low.		
☐ An	Address	s beir	ng provid	led fo	r th	e correspor	nden	e Info	rmation	of th	is application	on.		
Custom	er Numbe	r	20575	5										
Email Address docketing@fechlaw.com Add Email Remo					Remove	Email								
Applica	ation Ir	forr	nation	:										
Title of t	the Invent	ion	SELF	ALIG	NED	VERTICAL P	OWE	R MOS	FET WIT	H ENH	HANCED BAS	E REGION	N	
Attorney	Docket I	lumb	er 1138-	71				s	mall En	tity St	tatus Claime	ed 🗌		
Applicat	tion Type		Nonp	Nonprovisional										

2811

14

Sub Class (if any)

Suggested Figure for Publication (if any)

Subject Matter Suggested Class (if any)

Suggested Technology Center (if any) Total Number of Drawing Sheets (if any)

PTO/SB/14 (08-05)

Approved for use through 07/31/2006 OMB 0651-0032

Under the F	aperwork Reduction Act	of 1995, no persons	are required to respond to a collecti	on of information unless it contains a valid OMB control number				
Application Da	to Choot 27 C	ED 4 76 A	ttorney Docket Number	1138-71				
Аррисацоп Ба	ita Sileet 37 C	A 1.70	pplication Number					
Title of Invention	SELF ALIGNED	VERTICAL POV	VER MOSFET WITH ENHAN	CED BASE REGION				
Publication Inform	nation:							
Request Early	Publication (Fee	required at tir	ne of Request 37 CFR 1.2	19)				
and certify the	Request Not to Publish. I hereby request that the attached application not be published under 35 U.S.C. 122(b) and cartify that the invention disclosed in the attached application has not been and will not be the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months							
Representative Information: Representative Information and Provided for all praditioners having a power of allonney in the application. Providing this stormation in the Application District Section 2 of CRR 123. Enter either Customer Namber or compete the Representative Name section below. If both sections are completed the Customer Namber will be used for the Representative Information during processing.								
Please Select One	: Ousto	mer Number	US Patent Practitione	US Representative (37 CFR 11.9)				
Customer Number 20575								

Domestic Priority Information:

This section allows for the applicant to claim benefit under 35 U.S.C. 119(e), 120, 121, or 365(c). Providing this information in the application data sheet constitutes the specific reference required by 35 U.S.C. 119(e) or 120, and 37 CFR 1.78(a)(2) or CFR 1.78(a)

(4), and need not	ouletwise b	s made part or t	ne specification.					
Prior Applicat	ion Status	Patented			Remove			
Application Cont		inuity Type	Prior Application Number	Filing Date (YYYY-MM-DD)	Patent Numbe	Issue Date (YYYY-MM-DD)		
	Division o	ıf	08106406	1993-08-13	5801417	1998-09-01		
Prior Applicat	ion Status	Patented		Remove				
Application Number	Con	inuity Type	Prior Application Number	Filing Date (YYYY-MM-DD)	Patent Numbe	Issue Date (YYYY-MM-DD)		
08106406 Division of		ıf	07927169	1992-08-07	5283201	1994-02-01		
Prior Applicat	ion Status	Patented				Remove		
Application Number	Con	inuity Type	Prior Application Number	Filing Date (YYYY-MM-DD)	Patent Numbe	Issue Date (YYYY-MM-DD)		
07927169	Continua	ion in part of	07852932	1992-03-13	5262336	1993-11-16		
Prior Applicat	ion Status	Abandoned				Remove		
Application Number Con		Conf	inuity Type	Prior Application Number Filing Date (YYYY-		Date (YYYY-MM-DD)		
07852932 Continuation			of	07751441 1991-08-28				
Additional Domethe Add button.	estic Priori	y Data may l	be generated within	this form by selecting	, [Add		

Foreign Priority Information:

PTO/SB/14 (08-05)

Approved for use through 07/31/2006 OMB 0651-0032 U.S. Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number								
Application Data Sheet 37 CFR 1.76		Attorney Docket Number	1138-71					
		Application Number						
Title of Invention	SELF ALIGNED VERTICAL F	OWER MOSFET WITH ENHAN	ICED BASE REGION					

This section allows for the applicant to claim benefit of foreign priority and to identify any prior foreign application for which priority is not claimed. Providing this information in the application data sheet constitutes the claim for priority as required by 35 U.S.C. 119(b). and 37 CFR 1.55(a).

			Remove					
Application Number	Country i	Parent Filing Date (YYYY-MM-DD)	Priority Claimed					
			O Yes ⊛ No					
Additional Foreign Priority Data may be generated within this form by selecting the Add button.								

Add button.			7.00
Assignee Inform	nation:		
	in the application data sheet does signment recorded in the Office	not substitute for compliance w	with any requirement of part 3 of Title 37
Assignee 1			Remove
If the Assignee is an O	rganization check here.	₹	
Organization Name	MICROSEMI CORP - POWER	PRODUCTS GROUP	
Mailing Address Info	rmation:		
Address 1	405 SW Columbia Street		
Address 2			
City	Bend	State/Province	OR
Country i US		Postal Code	97702
Phone Number	(541) 382-8028	Fax Number	(541) 389-1241
Email Address	docketing@techlaw.com		
Additional Assignee D button.	ata may be generated within t	his form by selecting the Ac	dd Add

Signature:

A signature of the applicant or representative is required in accordance with 37 CFR 1.33 and 10.18. Please see 37 CFR 1.4(d) for the form of the signature.									
Signature	/alexander c. johnson,	jr./	Date (YYYY-MM-DD)	2006-11-03					
First Name	Alexander	Last Name	Johnson, Jr.	Registration Number	29396				

This collection of information is required by 37 CFR 1.76. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 23 minutes to complete, including gathering, preparing, and submitting the completed application data sheet form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Privacy Act Statement

The Privacy Act of 1974 (P. 9.5579) requires that you be given certain information in connection with your submission of the attends form maked to applicat application or partial. Accordingly, pressured to be requiremented in the Act please to advised that (1) the general authory for the received on the sinternation as 3.0 LS C. (3)(y); (2) I termiting of the information solicided is solicitary, and (3) the privilegal purpose for which the information is solicited in solicitary. Among the privilegal purpose for which the information is used by the U.S. Pleast and Traderison (filter is processed and the information is used by the U.S. Pleast and Traderison (filter is processed privilegal purpose). The processes are designed information, the U.S. Pleast and Traderison (filter is processed privilegal purpose).

The information provided by you in this form will be subject to the following routine uses:

- The information on this form will be treated confidentially to the extent allowed under the Freedom of Information Act (5 U.S.C. 552) and the Privacy Act (5 U.S.C. 552a). Records from this system of records may be disclosed to the Department of Justice to determine whether the Freedom of Information Act requires disclosure of these records.
- A record from this system of records may be disclosed, as a routine use, in the course of presenting evidence to a court, magistrate, or administrative tribunal, including disclosures to opposing counsel in the course of settlement negotiations.
- A record in this system of records may be disclosed, as a routine use, to a Member of Congress submitting a request involving an individual, to whom the record pertains, when the individual has requested assistance from the Member with respect to the subject matter of the record.
- 4. A record in this system of records may be disclosed, as a routine use, to a contractor of the Agency having need for the information in order to perform a contract. Recipients of information shall be required to comply with the requirements of the Privacy Act of 1974, as amended oursurant to 5 LPSC 4550/am.
- A record related to an International Application filed under the Patent Cooperation Treaty in this system of records may be disclosed, as a routine use, to the International Bureau of the World Intellectual Property Organization, pursuant to the Patent Cooperation Treaty.
- A record in this system of records may be disclosed, as a routine use, to another federal agency for purposes of National Security review (35 U.S.C. 191) and for review pursuant to the Atomic Energy Act (42 U.S.C. 219(c)).
- 7 A record from this system of records may be disclosed, as a routine use, to the Administrator, Clemental Services, or hisher designee, using an impedition of records conducted by GSAs apart of that agency's resopability to recommend improvements in record management practices and programs, under authority of 44 U.S.C. 2004 and 2006. Such disclosure shall be made in accordance with the CSA negliations operating impaction of records for this propose, and any other relevant (a.e., CSA or Commeto) directive.
- 8. A record from this system of records may be disclosed, as a multime use, to the public after either publication of the application pursuant to 3 to U.S. C. 151. Further, a record may be disclosed, adulged to the imitations of 37 CFR 1.14, as a routine use, to the public if the record was filled in an application which became absended or in which the proceedings were terminated and which application to reference by either application to reference by either application port to public impectations or an issued.
- A record from this system of records may be disclosed, as a routine use, to a Federal, State, or local law enforcement agency, if the USPTO becomes aware of a violation or potential violation of law or regulation.